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DEC 10 2010

## PATENT ABSTRACTS OF JAPAN

(11)Publication number : 51-150980

(43)Date of publication of application : 24.12.1976

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(51)Int.Cl. H01L 29/78  
H01L 29/62

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(21)Application number : 50-074511

(71)Applicant : HITACHI LTD

(22)Date of filing : 20.06.1975

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### (54) SEMICONDUCTOR DEVICE

#### (57)Abstract:

PURPOSE: How to fabricate a semiconductor invariable memory FET of storage mechanism in silicon nitrogen film, the fabrication of which is simple and high integration and high speed motion of which are also possible.